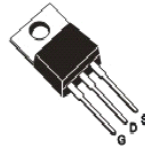


1.Features

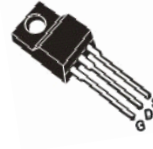
- $V_{DS(V)}=600V$
- $I_D=2A$
- $R_{DS(ON)}=4.5\Omega$

2.Pinning information

Pin	Symbol	Description
1	G	GATE
2	D	DRAIN
3	S	SOURCE



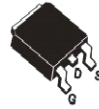
TO-220



TO-220F



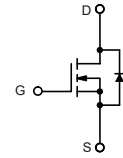
TO-251



TO-252



TO-223



N-Channel

3.Absolute Maximum Ratings $T_c=25^\circ C$

Parameter		Symbol	Rating	Units
Drain-source Voltage		V_{DS}	600	V
gate-source Voltage		V_{GS}	± 30	V
Continuous Drain Current	$T_c=25^\circ C$	I_D	2	A
Continuous Drain Current	$T_c=100^\circ C$	I_D	1.25	A
Drain Current – Pulsed ①		I_{DM}	8	A
Power Dissipation	TO-220	P_D	54	W
	TO-251/TO-252		45	W
Junction Temperature		T_J	150	$^\circ C$
Storage Temperature		T_{STG}	-55 to 150	$^\circ C$
Single Pulse Avalanche Energy ②		E_{AS}	120	mJ



4. Thermal resistance rating

Parameter	Symbol	MAX		Units
		TO-220	TO-220F	
Thermal Resistance Junction-lead	R_{thJC}	2.31	5.43	°C/W
Thermal Resistance Junction-ambient	R_{thJA}	62.5	62.5	°C/W



5. Electrical Characteristic (T_c=25°C unless otherwise noted)

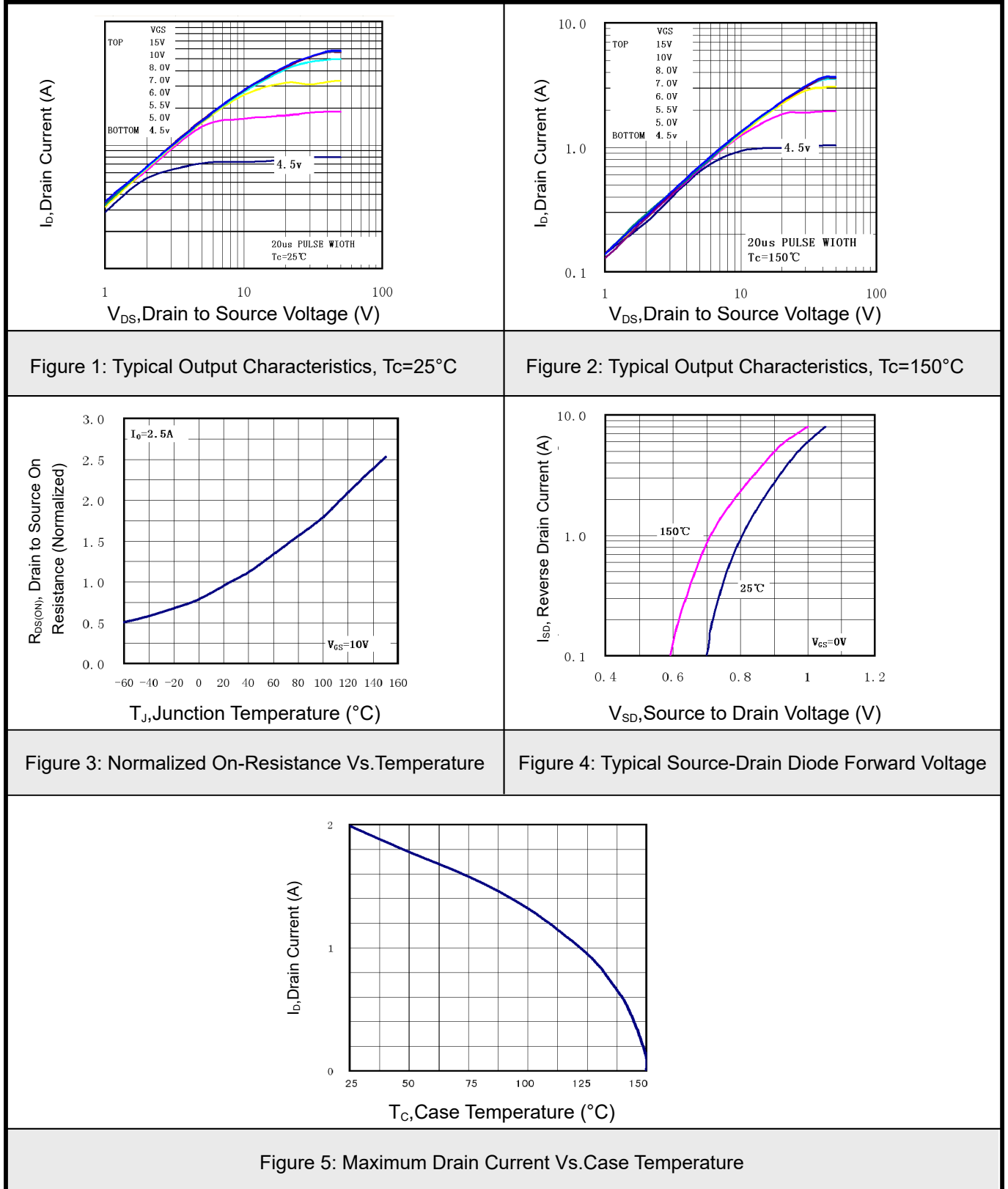
Parameter	Symbol	Conditions	Min	Typ	Max	Units
Drain-source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	600			V
Breakdown Voltage Temperature Coefficient	$\frac{\Delta BV_{DSS}}{\Delta T_J}$	I _D =250μA Referenced to 25°C		0.6		V/°C
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	2		4	V
Drain-source Leakage Current	I _{DSS}	V _{DS} =600V, V _{GS} =0V, T _J =25°C			25	μA
		V _{DS} =480V, V _{GS} =0V, T _J =125°C			250	μA
Forward Transconductance	g _{fs}	V _{GS} =40V, I _D =1A ③		1.5		S
Gate-body Leakage Current (V _{DS} =0)	I _{GSS}	V _{GS} =±30V			±100	nA
Static Drain-source On Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =1A ③		4.2	4.5	Ω
Input capacitance	C _{iss}	V _{GS} =0V, V _{DS} =25V, f=1MHz		320		pF
Turn -Off Delay Time	t _{D(off)}	V _{DD} =300V, I _D =2A, R _G =25Ω ③		24		ns
Total Gate Charge	Q _g	I _D =2A, V _{DS} =480V, V _{GS} =10V ③		7.2		nC
Gate-to-Source Charge	Q _{gs}			4.3		nC
Gate-to-Drain Charge	Q _{gd}			1.6		nC
Continuous Diode Forward Current	I _S				2	A
Diode Forward Voltage	V _{SD}	T _J =25°C, I _S =2A, V _{GS} =0V ③			1.4	V
Reverse Recovery Time	t _{rr}	T _J =25°C, I _F =2A		380		ns
Reverse Recovery Charge	Q _{rr}	di/dt=100A/μs ③		0.9		uC

Notes:

- ① Repetitive rating: Pulse width limited by maximum junction temperature.
- ② Starting T_J=25°C, V_{DD}=50V, L=56mH, R_G=25Ω, I_{AS}=2A.
- ③ Pulse Test : Pulse width ≤ 300μs, Duty cycle ≤ 2%.

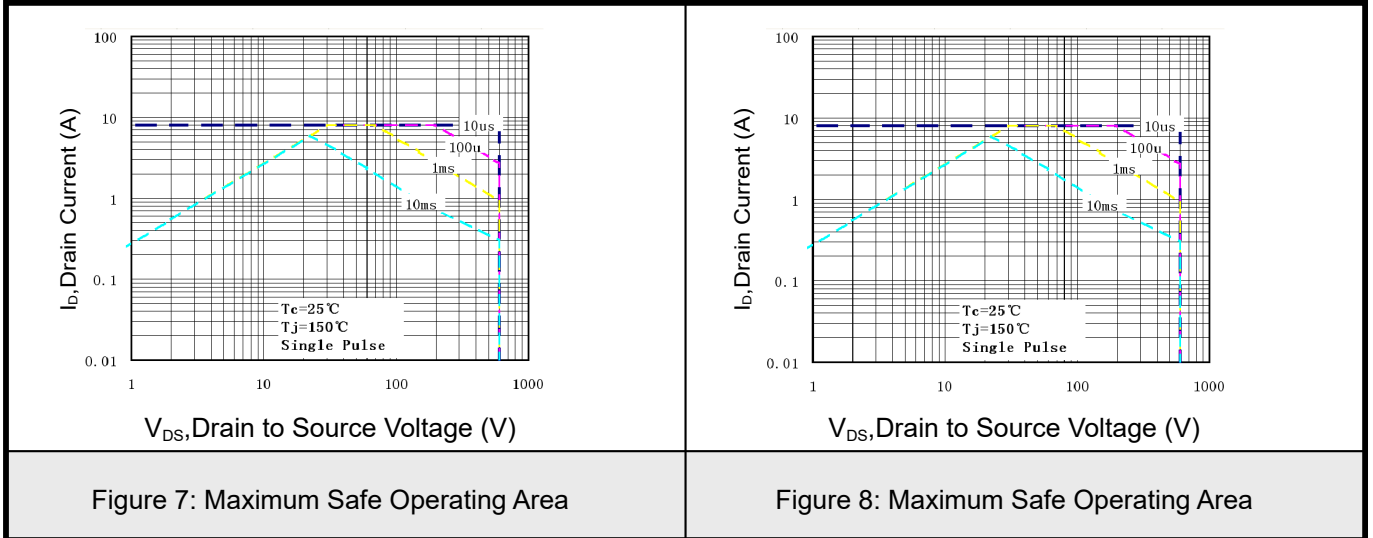


6.1 Typical characteristic



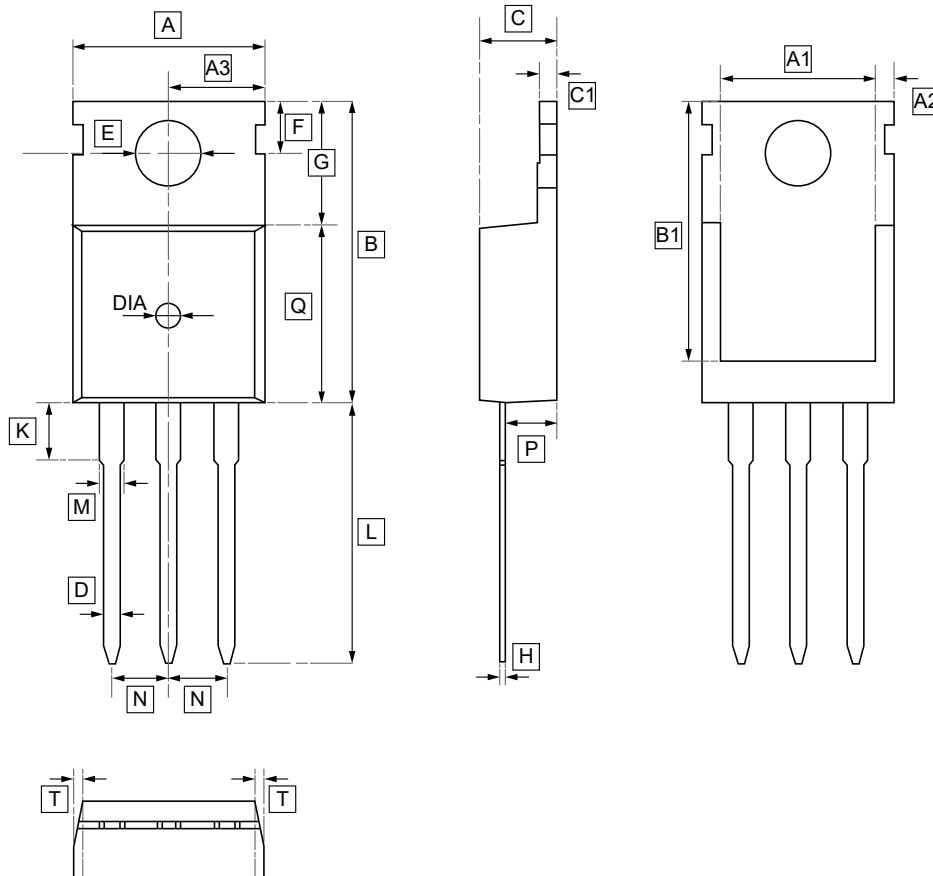


6.2 Typical characteristic





7.1 TO-220 Package Outline Dimensions



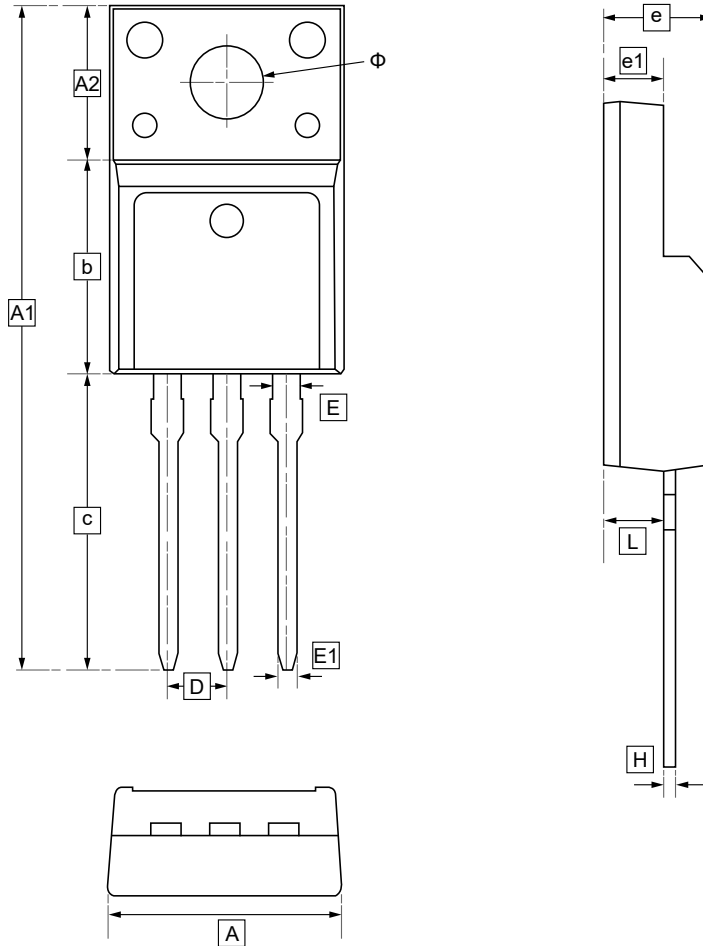
DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	A3	B	B1	C	C1	D	E	F	G
Min	9.7	8.44	1.05	4.8	15.4	12.9	4.28	1.1	0.6	3.4	2.65	5.2
Max	10.3	8.84	1.25	5.2	16.2	13.5	4.68	1.5	1.0	3.8	3.25	5.8

Symbol	H	K	L	L1	M	N	P	Q	T	DIA
Min	0.4	2.9	12.8	2.7	1.15	2.49	2.1	8.7	W:0.35	⊙1.5
Max	0.6	3.3	13.6	3.3	1.35	2.59	2.7	9.3		(deep 0.2)



7.2 TO-220F Package Outline Dimensions



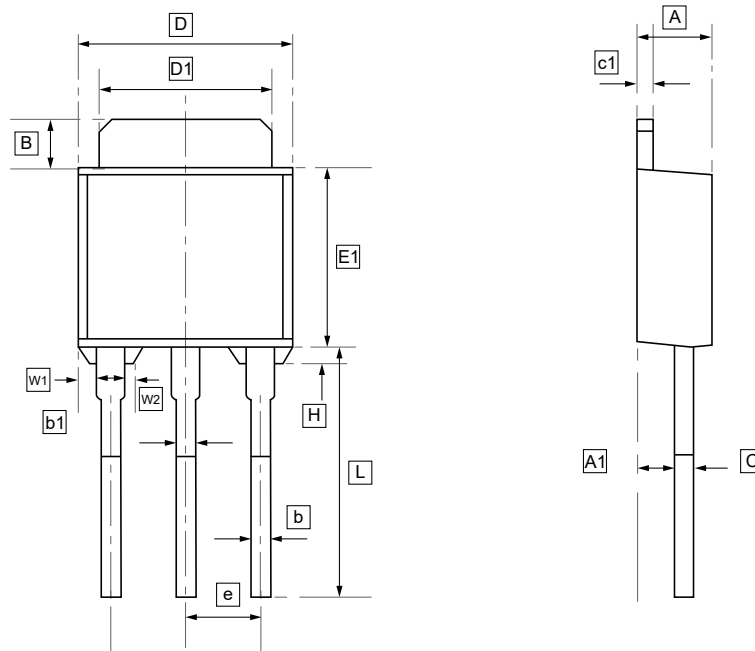
DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	c	D	E	E1	Φ	e	e1	L
Min	10.00	28.80	6.58	9.12	12.95	2.54	1.15	0.75	3.13	4.50	2.40	2.50
Max	10.20	29.20	6.78	9.32	13.25		1.25	0.85	3.23	4.70	2.60	2.70

Symbol	H
Min	0.45
Max	0.55



7.3 TO-251T (IPAK) Package Outline Dimensions

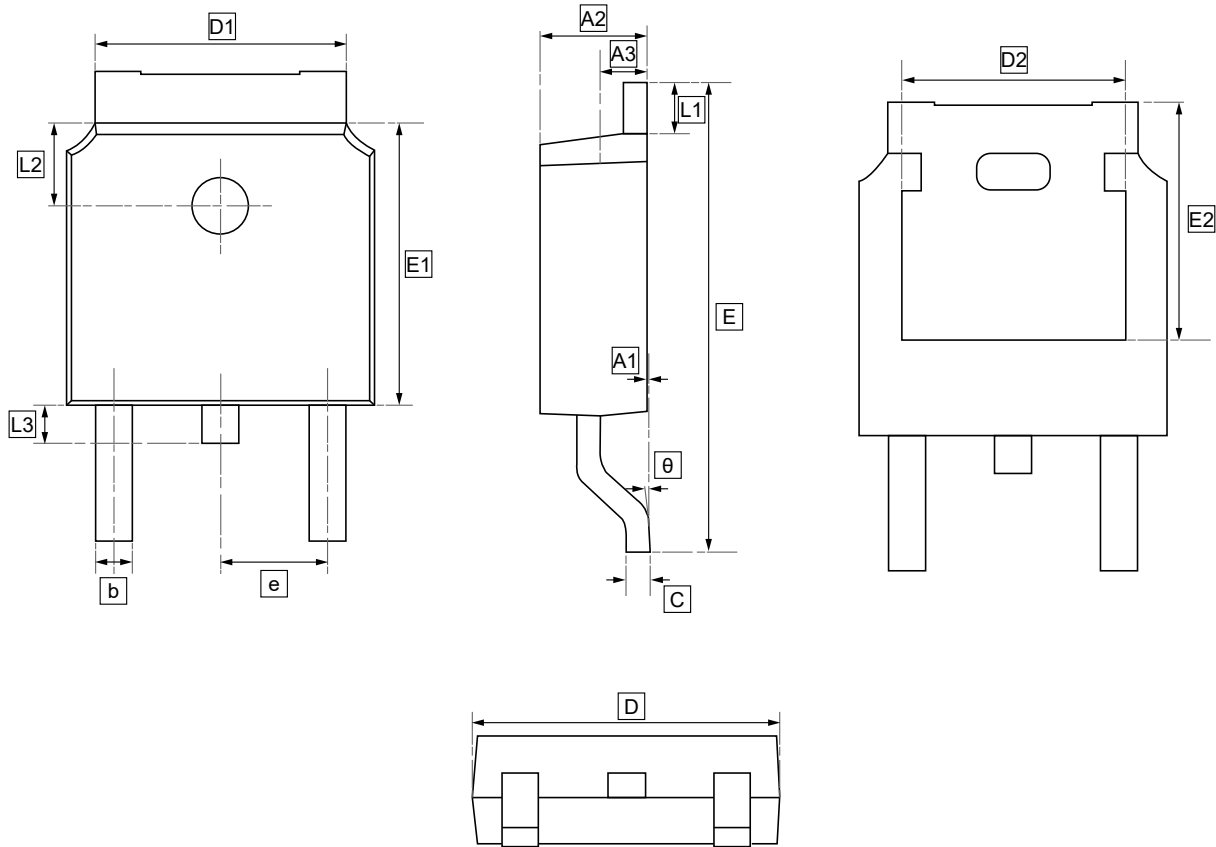


DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	B	b	b1	c	c1	D	D1	E	e	L	H	W1	W2
Min	2.10	0.95	0.80	0.50	0.70	0.45	0.45	6.35	5.10	5.30	2.25	7.00	0.35	0.30	0.20
Max	2.50	1.30	1.25	0.80	0.80	0.70	0.70	6.80	5.50	6.30	2.35	9.20	0.45	0.50	0.40



7.4 TO-252 Package Outline Dimensions

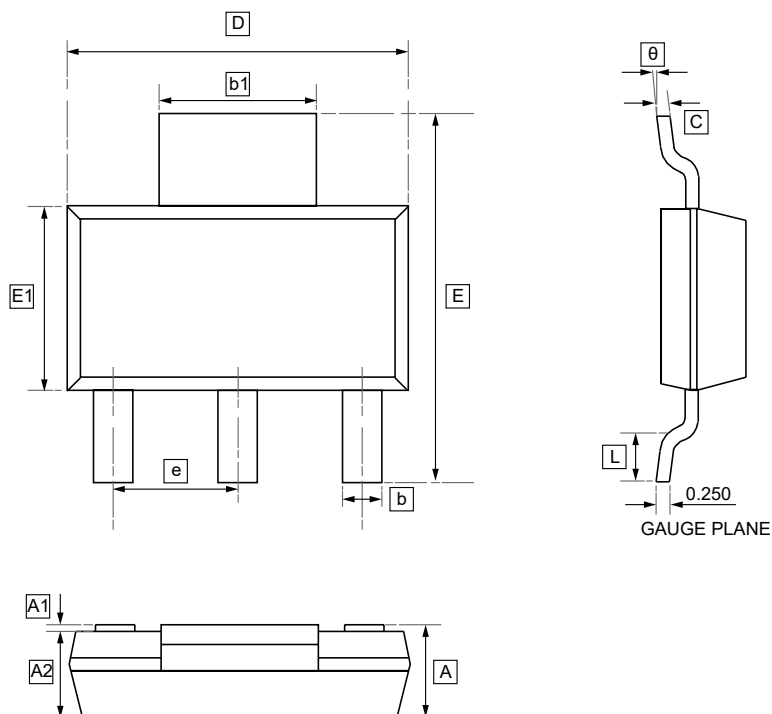


DIMENSIONS (mm are the original dimensions)

Symbol	A1	A2	A3	b	c	D	D1	D2	E	E1	E2	e	L1	L2	L3	θ
Min	0.00	2.18	0.90	0.65	0.46	6.35	4.95	4.32	9.40	5.97	5.21	2.286	0.89	1.70	0.60	0.00
Max	0.13	2.39	1.10	0.85	0.61	6.73	5.46	4.90	10.41	6.22	5.38	BSC	1.27	1.90	1.00	8.00



7.5 SOT-223 Package Outline Dimensions

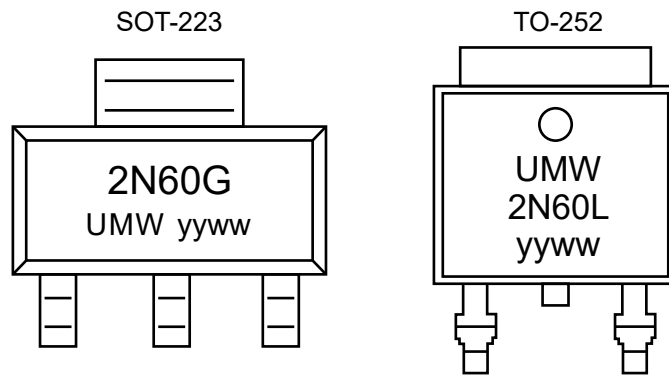


DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	b1	c	D	E	E1	e	L	θ
Min	-	0.020	1.500	0.660	2.900	0.230	6.300	6.700	3.300	2.300	0.750	0°
Max	1.800	0.100	1.700	0.840	3.100	0.350	6.700	7.300	3.700	BSC	-	10°



8. Ordering information



yy: Year Code
ww: Week Code

Order Code	Package	Base QTY	Delivery Mode
UMW 2N60G	SOT-223	2500	Tape and reel
UMW 2N60L	TO-252	2500	Tape and reel



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